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September 2013



## FGPF15N60UNDF 600 V, 15 A Short Circuit Rated IGBT

#### Features

- Short Circuit Rated 10us
- High Current Capability
- High Input Impedance
- Fast Switching
- · RoHS Compliant

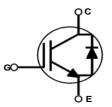
## **General Description**

Using advanced NPT IGBT technology, Fairchild's the NPT IGBTs offer the optimum performance for low-power inverterdriven applications where low-losses and short-circuit ruggedness features are essential, such as sewing machine, CNC, motor control and home appliances.

### Applications

· Sewing Machine, CNC, Home Appliances, Motor Control





#### **Absolute Maximum Ratings**

Symbol	Descriptio	on	Ratings	Unit
V <sub>CES</sub>	Collector to Emitter Voltage		600	V
V <sub>GES</sub>	Gate to Emitter Voltage		± 20	V
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	30	A
	Collector Current	@ T <sub>C</sub> = 100°C	15	A
I <sub>CM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	45	A
I <sub>F</sub>	Diode Forward Current	@ T <sub>C</sub> = 25 <sup>o</sup> C	15	A
	Diode Forward Current	@ T <sub>C</sub> = 100°C	7.5	A
PD	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	42	W
١D	Maximum Power Dissipation	@ T <sub>C</sub> = 100°C	17	W
TJ	Operating Junction Temperature		-55 to +150	°C
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

#### **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	3.0	°C/W
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	-	4.9	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)	-	62.5	°C/W

Notes:

2: Mountde on 1" square PCB (FR4 or G-10 material)

		Package	-		Width	Quantity		
		TO-220F					50ea	
Electric	al Chai	racteristics of t	he IGBT <sub>Tc=</sub>	25°C unless otherwise noted				
Symbol			Tes	Test Conditions		Тур.	Max.	Unit
Off Charac	teristics				·			
BV <sub>CES</sub>	Collector	to Emitter Breakdown V	oltage V <sub>GE</sub> = 0 V,	I <sub>C</sub> = 250 μA	600	-	-	V
I <sub>CES</sub>		Cut-Off Current		s, V <sub>GE</sub> = 0 V	-	-	1	mA
I <sub>GES</sub>	G-E Leak	age Current		$V_{CE} = 0 V$	-	-	±10	μA
On Charac	toristics				1	1		1
V <sub>GE(th)</sub>		shold Voltage	I <sub>C</sub> = 15 mA	, V <sub>CE</sub> = V <sub>GE</sub>	5.5	6.8	8.5	V
		0.1	-	V <sub>GE</sub> = 15 V	-	2.2	2.7	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage		lter and	V <sub>GE</sub> = 15 V,	-	2.7	-	V
			0	-				
Dynamic C C <sub>ies</sub>	haracteris					619	1	pF
	- · · ·	apacitance	V <sub>CE</sub> = 30 \	V <sub>CE</sub> = 30 V, V <sub>GE</sub> = 0 V,		80	_	
C <sub>oes</sub>	-	Transfer Capacitance	f = 1MHz	,	-	24	-	pF pF
ores	11010100						<u> </u>	P
Switching	1						1	
t <sub>d(on)</sub>		Delay Time			-	9.3	-	ns
t <sub>r</sub>	Rise Time	9				9.8	-	ns
t <sub>d(off)</sub>		Delay Time	$V_{\rm CC} = 400$	V, $I_{\rm C} = 15$ A,	-	54.8	-	ns
t <sub>f</sub>	Fall Time		R <sub>G</sub> = 10 Ω Inductive I	, V <sub>GE</sub> = 15 V, .oad, T <sub>C</sub> = 25°C	-	9.9	12.8	ns
Eon		Switching Loss			-	0.37	-	mJ
E <sub>off</sub>		Switching Loss			-	0.067	-	mJ
E <sub>ts</sub>		ching Loss			-	0.44	-	mJ
t <sub>d(on)</sub>		Delay Time			-	8.9	-	ns
t <sub>r</sub>	Rise Time				-	9.9	-	ns
t <sub>d(off)</sub>		Delay Time		V, $I_{\rm C} = 15  \text{A}$ ,	-	56.6	-	ns
t <sub>f</sub>	Fall Time			, V <sub>GE</sub> = 15 V, .oad, T <sub>C</sub> = 125°C	-	13.2	-	ns
E <sub>on</sub>		Switching Loss			-	0.54	-	mJ
E <sub>off</sub>		Switching Loss			-	0.11	-	mJ
E <sub>ts</sub>	Total Swit	ching Loss			-	0.65		mJ
T <sub>sc</sub>	Short Circ	cuit Withstand Time	$V_{CC} = 350$ $R_{G} = 100$ $g$ $T_{C} = 150^{\circ}$	Ω, V <sub>GE</sub> = 15 V,	10	-	-	μs

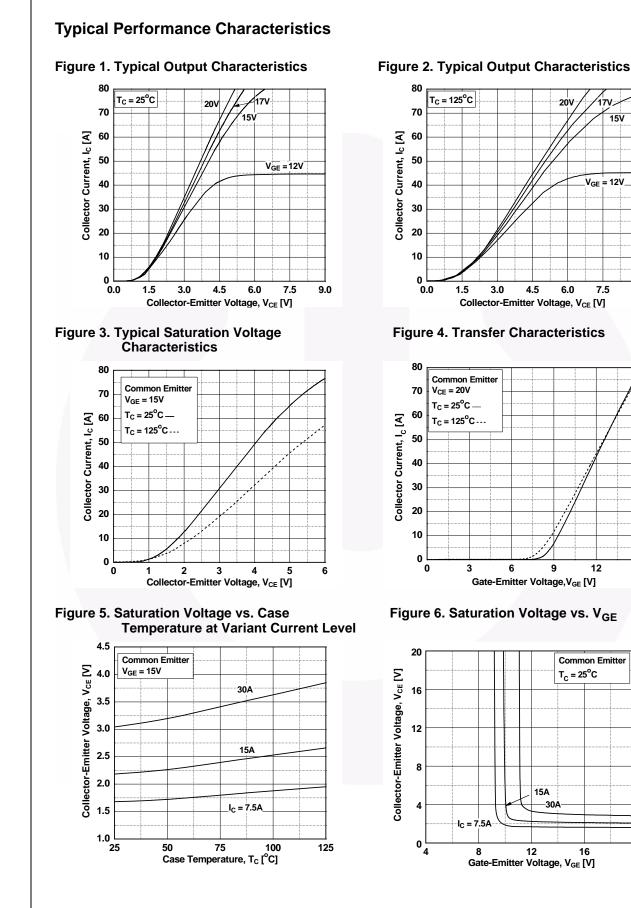
## Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

Qg	Total Gate Charge		-	43	-	nC
Q <sub>ge</sub>	Gate to Emitter Charge	V <sub>CE</sub> = 400 V, I <sub>C</sub> = 15 A, V <sub>GE</sub> = 15 V	-	6	-	nC
Q <sub>gc</sub>	Gate to Collector Charge		-	26	-	nC

## Electrical Characteristics of the Diode $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit
V <sub>FM</sub> Diode Forward Voltage	Diode Forward Voltage	I <sub>F</sub> = 15 A	$T_{C} = 25^{\circ}C$	-	1.6	2.2	V
	2.040 Formard Formage	·	T <sub>C</sub> = 125⁰C	-	1.5	-	
t <sub>rr</sub>	Diode Reverse Recovery Time	$I_{\rm F} = 15$ A, $dI_{\rm F}/dt = 200$ A/µs	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	82.4		ns
11			T <sub>C</sub> = 125⁰C	-	142	-	
Q.,	Q <sub>rr</sub> Diode Reverse Recovery Charge		$T_{C} = 25^{\circ}C$	-	213	-	nC
			T <sub>C</sub> = 125°C	-	541	-	

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20V

17V

V<sub>GE</sub> = 12V

7.5

9.0

6.0

15V

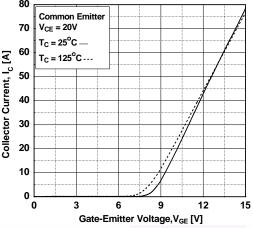
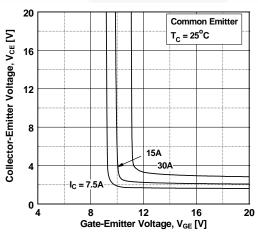


Figure 6. Saturation Voltage vs. V<sub>GE</sub>



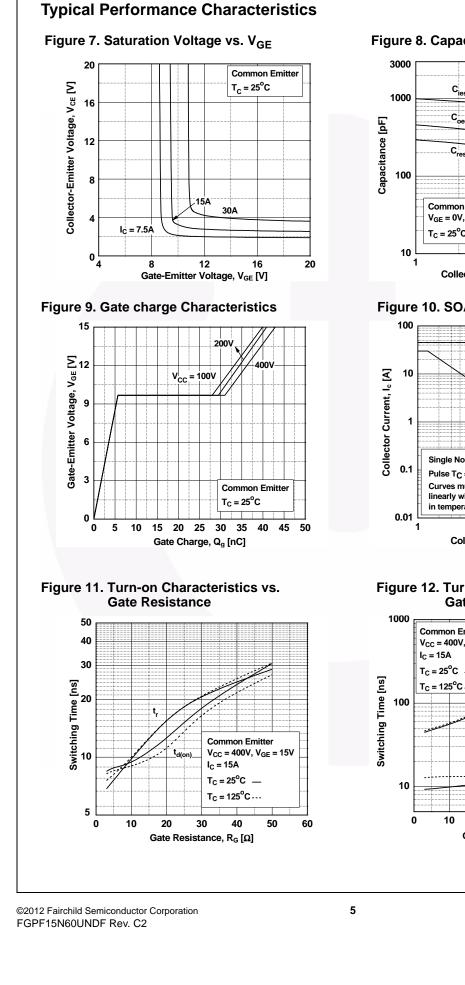
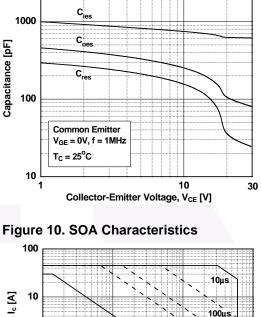


Figure 8. Capacitance Characteristics



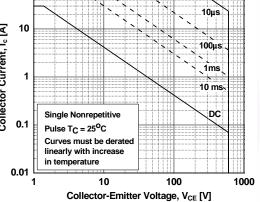
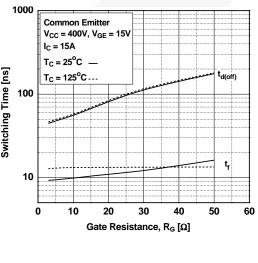
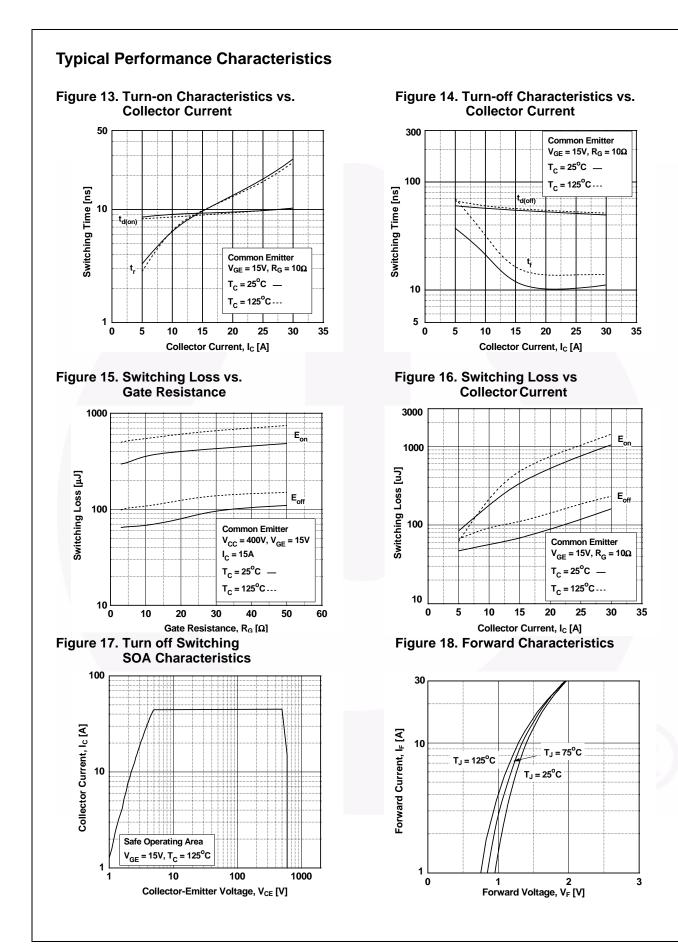


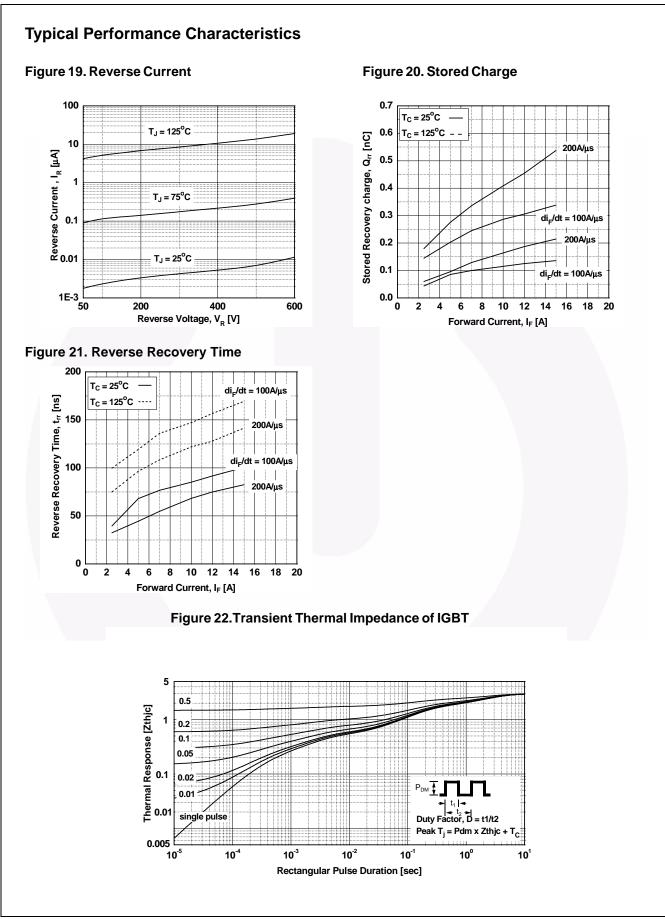
Figure 12. Turn-off Characteristics vs. Gate Resistance

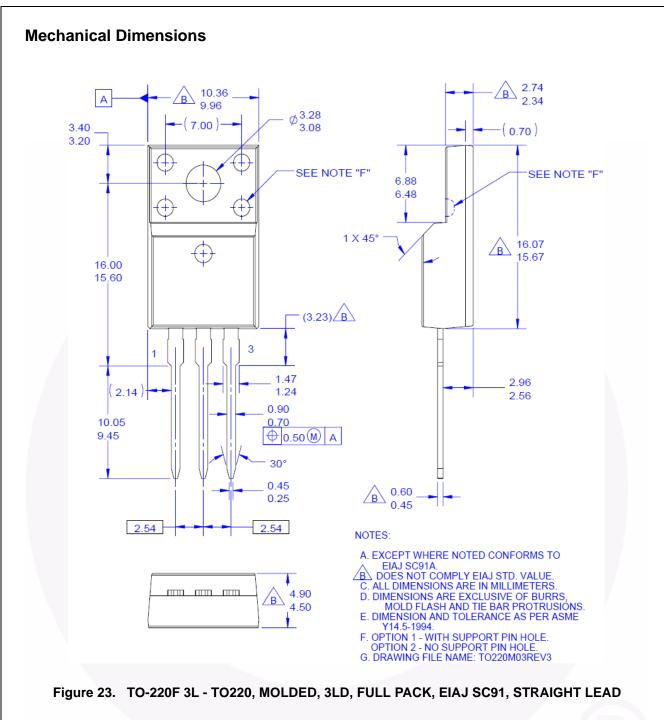


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**Dimensions in Millimeters** 

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